N-Channel 200-V (D-S) 150°C MOSFET

CHARACTERISTICS

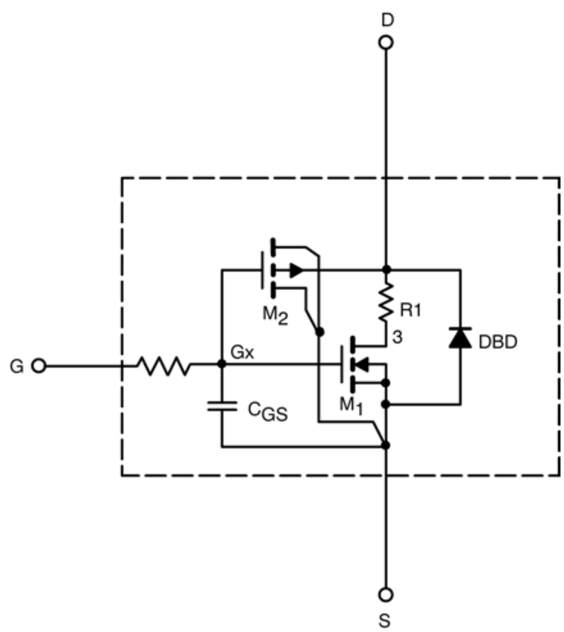
- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the −55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the −55 to 125°C temperature ranges under the pulsed 0-V to 5-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

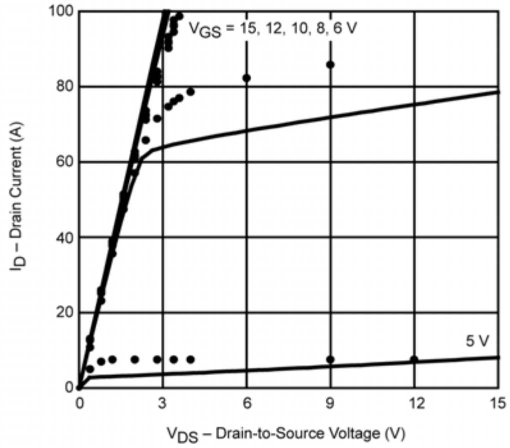


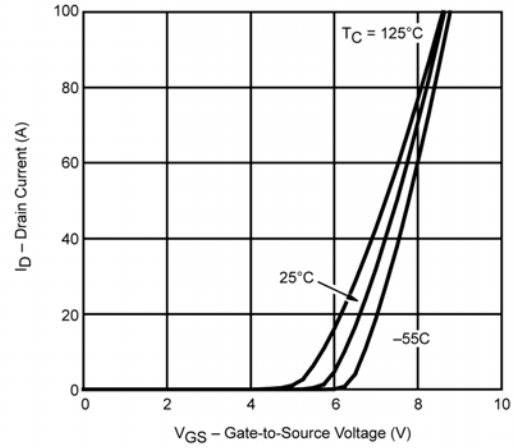
This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

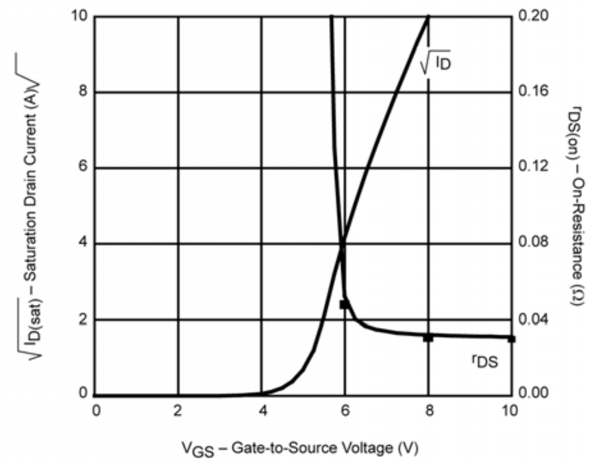
SPECIFICATIONS (T_J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	**Symbol**	**Test Condition**	**Simulated Data**	**Measured Data**	**Unit**
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, I_D = 250μA	4		V
On-State Drain Current[a]	$I_{D(on)}$	$V_{DS} \geq$ 10V, V_{GS} = 10V	174		A
Drain-Source On-State Resistance[a]	$r_{DS(on)}$	V_{GS} = 15V, I_D = 20A	0.031	0.031	Ω
		V_{GS} = 10V, I_D = 20A	0.0313	0.0305	
		V_{GS} = 10V, I_D = 20A, T_J = 100°C	0.048		
		V_{GS} = 10V, I_D = 20A, T_J = 150°C	0.059		
Forward Voltage[a]	V_{SD}	I_F = 20A, V_{GS} = 0 V	0.90	0.86	V
Dynamic[b]					
Input Capacitance	C_{iss}	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz	4534	4220	pF
Output Capacitance	C_{oss}		396	400	
Reverse Transfer Capacitance	C_{rss}		201	185	
Total Gate Charge[c]	Q_g	V_{DS} = 100V, V_{GS} = 15V, I_D = 50A	113	123	nC
		V_{DS} = 100V, V_{GS} = 10V, I_D = 50A	82	81	
Gate-Source Charge[c]	Q_{gs}		21	21	
Gate-Drain Charge[c]	Q_{gd}		27	27	

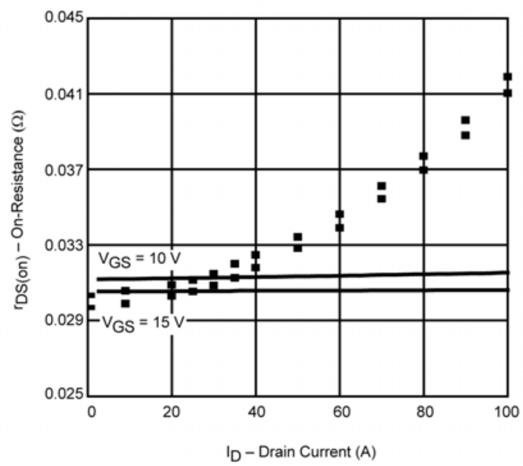
Notes
a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

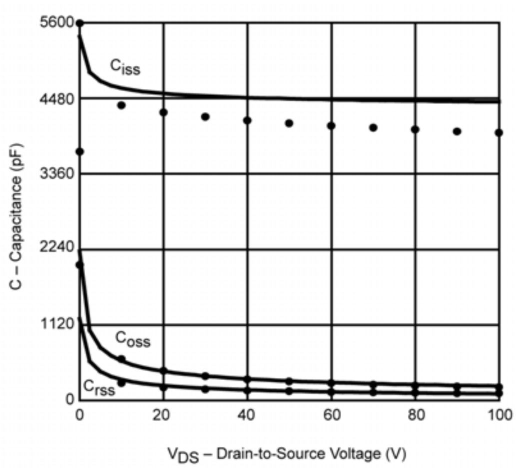
COMPARISON OF MODEL WITH MEASURED DATA (T_J=25°C UNLESS OTHERWISE NOTED)

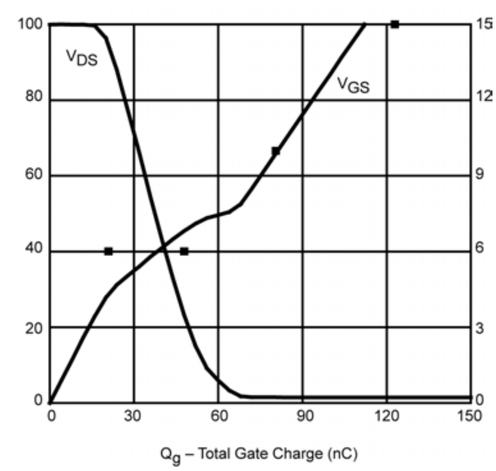












Note: Dots and squares represent measured data.

Disclaimer

All product specifications and data are subject to change without notice.

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